EFC6605R

N-Channel Power MOSFET 20V, 10A, 13.3mΩ, Dual EFCP



- 2.5V drive
- Protection diode in
- Halogen free compliance

Applications

• Lithium-ion battery charging and discharging switch

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Value	Unit
Source to Source Voltage	V _{SSS}		20	V
Gate to Source Voltage	V _{GSS}		±10	V
Source Current (DC)	IS		10	А
Source Current (Pulse)	ISP	PW≤10µs, duty cycle≤1%	60	А
Total Dissipation	Ρ _T	When mounted on ceramic substrate (5000mm ² ×0.8mm)	1.6	W
Junction Temperature	т _і		150	°C
Storage Temperature	Tstg		- 55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Thermal Resistance Ratings

Parameter	Symbol	Value	Unit
Junction to Ambient	R _{θJA}	78.1	°C /W
When mounted on ceramic substrate (5000mm ² ×0.8mm)			

Electrical Characteristics at $Ta = 25^{\circ}C$

Parameter	Symbol	Canditi	Value			Unit	
Parameter	Symbol	Conditions		min	typ	max	Unit
Source to Source Breakdown Voltage	V(BR)SSS	I _S =1mA, V _{GS} =0V	Test Circuit 1	20			V
Zero-Gate Voltage Source Current	ISSS	V _{SS} =20V, V _{GS} =0V	Test Circuit 1			1	μΑ
Gate to Source Leakage Current	IGSS	V _{GS} =±8V, V _{SS} =0V	Test Circuit 2			±1.0	μA
Gate Threshold Voltage	V _{GS} (th)	V _{SS} 10V, I _S =1mA	Test Circuit 3	0.5		1.3	V
Forward Transconductance	9FS	V _{SS} =10V, I _S =3A	Test Circuit 4		11.4		S
	RSS(on)1	IS=3A, VGS=4.5V	Test Circuit 5	8.8	11.1	13.3	mΩ
Static Source to Source On-State Resistance	RSS(on)2	IS=3A, VGS=4.0V	Test Circuit 5	9.1	11.4	13.7	mΩ
	RSS(on)3	IS=3A, VGS=3.8V	Test Circuit 5	9.3	11.6	13.9	mΩ
	RSS(on)4	IS=3A, VGS=3.1V	Test Circuit 5	10.0	12.5	15.6	mΩ
	RSS(on)5	IS=3A, VGS=2.5V	Test Circuit 5	11.1	13.9	17.4	mΩ

Continued on next page.

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

ON

• Common-drain type

• 2KV ESD HBM

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Parameter	Quarkal	Conditions	Value			11
	Symbol	Conditions	min	typ	max	Unit
Turn-ON Delay Time	t _d (on)			154		ns
Rise Time	tr			678		ns
Turn-OFF Delay Time	t _d (off)	VSS=10V, VGS=4.5V, IS=3A Test Circuit 6		44400		ns
Fall Time	tf			60800		ns
Total Gate Charge	Qg	V _{SS} =10V, V _{GS} =4.5V, I _S =10A Test Circuit 7		19.8		nC
Forward Source to Source Voltage	V _{F(S-S)}	IS=3A, VGS=0V Test Circuit 8		0.75	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

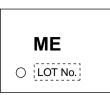
Ordering & Package Information

Device	Package	Shipping	note
EFC6605R-TR	EFCP	5,000 pcs. / reel	Pb-Free and Halogen Free

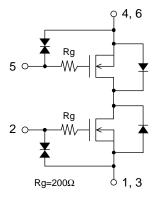
Packing Type: TR

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Marking

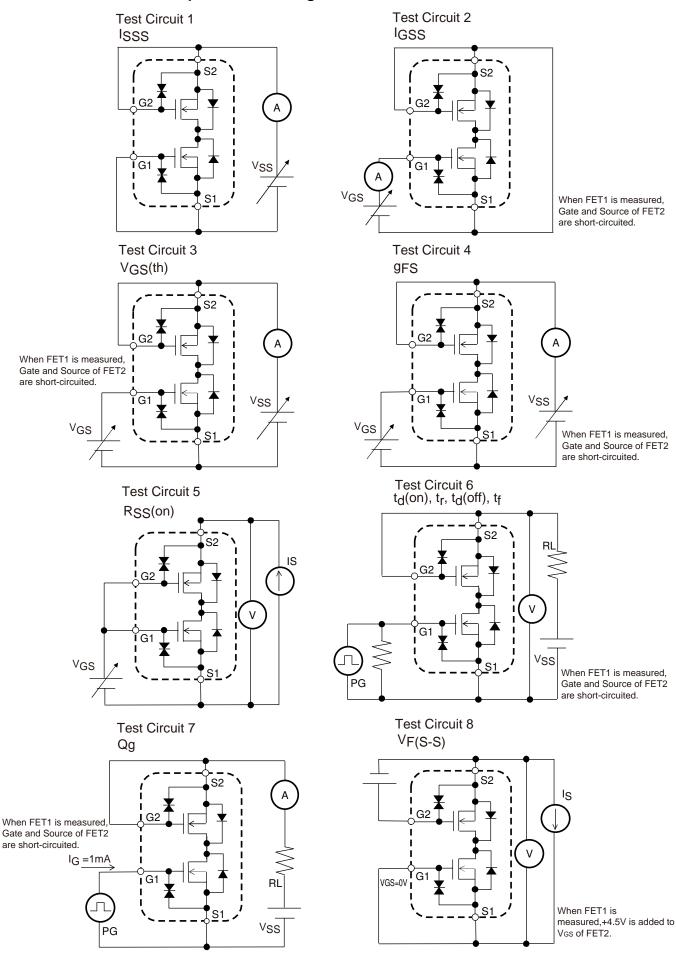


Electrical Connection

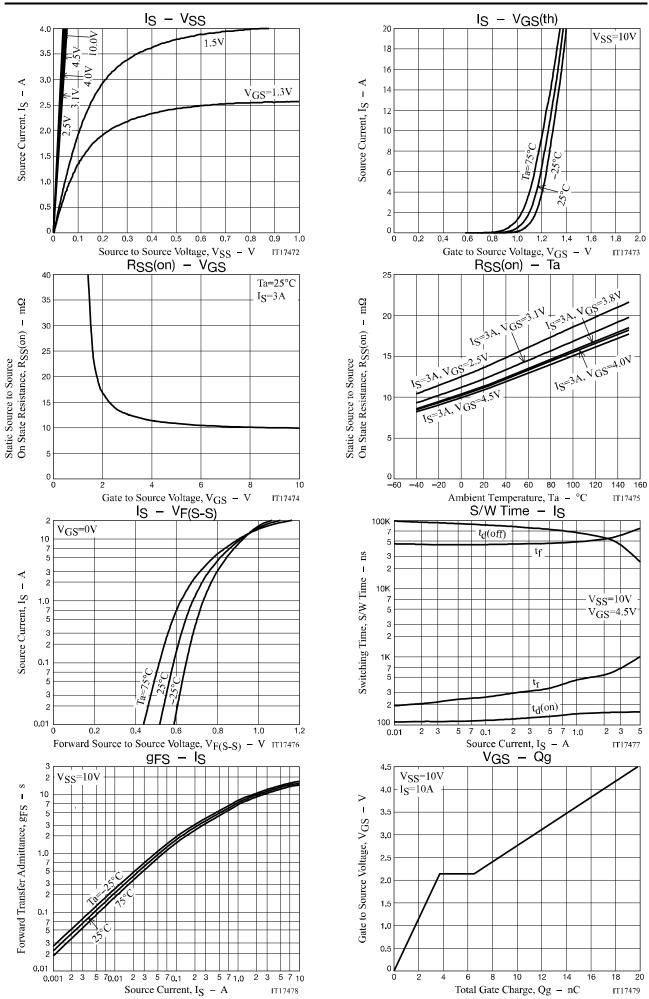


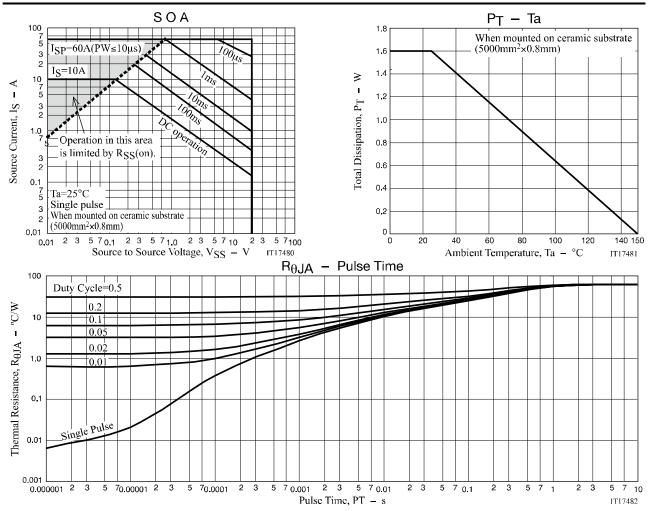
EFC6605R

Test circuits are example of measuring FET1 side



When FET2 is measured, the position of FET1 and FET2 is switched.

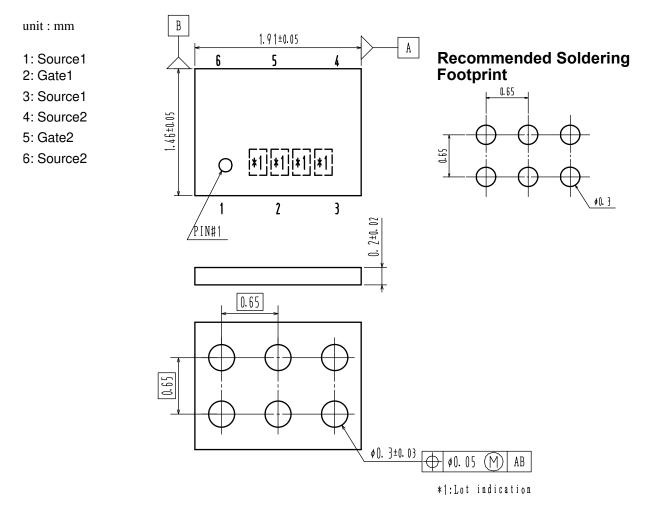




Package Dimensions

EFC6605R-TR

EFCP1915-6CE-020



Note on usage : Since the EFC6605R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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